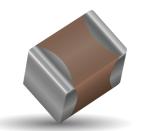
## COG (NPO) Dielectric, KGM Series



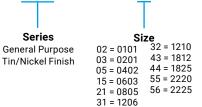




COG (NPO) is the most popular formulation of the "temperature-compensating," EIA Class I ceramic materials. Modern COG (NPO) formulations contain neodymium, samarium and other rare earth oxides.

COG (NP0) ceramics offer one of the most stable capacitor dielectrics available. Capacitance change with temperature is 0 ±30ppm/°C which is less than ±0.3% C from -55°C to +125°C. Capacitance drift or hysteresis for COG (NPO) ceramics is negligible at less than ±0.05% versus up to ±2% for films. Typical capacitance change with life is less than ±0.1% for COG (NPO), one-fifth that shown by most other dielectrics.

## **HOW TO ORDER KGM**



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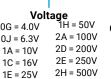


See Cap Chart

CG **Dielectric** 

CG = C0G

2J Voltage 1H = 50V 0G = 4.0V 0J = 6.3V





#### Capacitance Code Code (in pF) 2 Significant Digits +Number of zeros eg. $10\mu F = 106$

10nF = 103 47pF = 470

## Capacitance Tolerance

 $B = \pm .10pF (<10pF)^*$  $C = \pm .25pF (<10pF)*$  $D = \pm .50pF (<10pF)*$ F = ±1% (≥10pF)\* G = ±2% (≥10pF)\* J = ±5% (≥10pF)

K = ±10% (≥10pF)  $M = \pm 20\%$ 

\*COG only



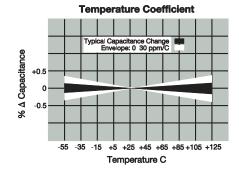


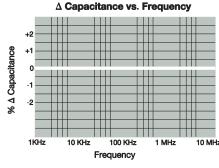


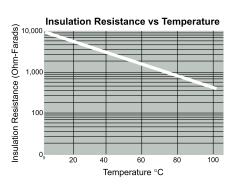
### **PACKAGING CODES**

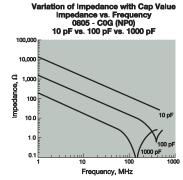
Code	EIA (inch)	IEC(mm)	7" Paper	7" Embossed	13" Paper	13"Embossed
02	0101	0402	Н		n/a	
03	0201	0603	Н		N	
05	0402	1005	Н		N	
15	0603	1608	Т		М	
21	0805	2012	Т	U	М	L
31	1206	3216	Т	U	М	L
32	1210	3225		U		L
43	1812	4532		V		S
44	1825	4564		V		S
55	2220	5750		V		S
56	2225	5763		V		S

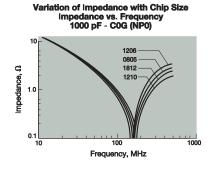
<sup>\*</sup>thickness determines paper or plastic embossed packaging

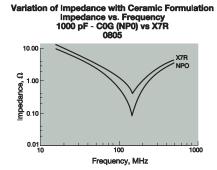












KYDCER3 | The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.kyocera-avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.

# COG (NPO) Dielectric, KGM Series





Parame	ter/Test	NP0 Specification Limits	Measuring Conditions							
	perature Range	-55°C to +125°C	Temperature Cycle Chamber							
•	itance Q	Within specified tolerance <30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	Freq.: 1.0 MHz ± 10% 1.0 kHz ± 10% fo Voltage: 1.0'	r cap > 1000 pF						
Insulation	Resistance	10,000MΩ or 500MΩ - $\mu$ F, whichever is less	Charge device with rated voltage for 60 ± 5 secs @ room temp/humidity							
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max)  Note: Charge device with 150% of rated voltage for 500V devices.							
	Appearance	No defects								
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Deflectio Test Time: 3							
Flexure	Q	Meets Initial Values (As Above)	V							
Stresses	Insulation Resistance	≥ Initial Value x 0.3	90 r	nm —						
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic solo 0.5 sec							
	Appearance	No defects, <25% leaching of either end terminal								
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Dip device in eutection	solder at 260°C for						
Resistance to	Q	Meets Initial Values (As Above)	60sec- onds. Store at room temperature for 24 ± 2hours before measuring electrical							
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	properties.	e measuring electrical						
	Dielectric Strength	Meets Initial Values (As Above)								
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes						
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes						
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes						
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes						
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 hours at roor							
	Appearance	No visual defects	-							
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twic							
Load Life	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	for 1000 hou  Remove from test cha	rs (+48, -0).						
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperatu before me	re for 24 hours						
	Dielectric Strength	Meets Initial Values (As Above)								
	Appearance	No visual defects								
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber s	et at 85°C ± 2°C/ 85% +						
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	5% relative humidi (+48, -0) with rated	ty for 1000 hours I voltage applied.						
numunty	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber and stabilize at room temperature for 24 ± 2 hours before measuring.							
	Dielectric Strength	Meets Initial Values (As Above)								

# **COG (NP0) Dielectric, KGM Series**





Page   Page   All Pager   Al		IZE dering	0101* Reflow Only	02 Refloy		Ref	0402 low/W	ave		Re	0603 eflow/W						0805 low/Wav	e				R	1206 eflow/W	/ave			
O   Congress   Process		-																									
MADD		-		_		_																					
Wilson	(L) Length	(in.)	(0.016±0.0008)	(0.024±	0.001)	(0.0	40±0.0	004)		(0.	063± 0.	006)				(0.0	79±0.00	8)			(0.126±0.008)						
Common   Composition   Control   C	W) Width																										
Timmen	W) Width	` ,				_												B)									
WYDC  16																											
C90   S   A	Terminal	\ /		_		_																		,			
GF  10												_		_													
12																											
T.   S																											
18																											
27										Α				В	В	В	В	В	В	В	В	В	В	В	В	В	
3.3									-																		
3																											
47																											
S																											
8.2 A A A A A A A A A A A A A A B B B B B																											
8.2																											
12		8.2		Α	Α		Α	Α	Α	Α	Α	Α	Α														
115																					-						
18																											
Text																											
1																					-						
33																											
47		33	Α	Α	Α	Α	Α	Α	Α	Α	Α	Α	Α	В	В	В	В	В	В	В	В	В	В	В	В	В	
56																											
68																											
82																											
100									-												-						
120																											
180		120												В			В				В	В				В	
220																											
270																											
330				A	A																						
390					<u> </u>	_																					
470																											
680		470							Α	Α			В	В	В	В	В	Е	Е	В	В	В	В	V	V	V	
R   R   R   R   R   R   R   R   R   R																					-						
1000					-																						
1200																											
1500																											
1800					<b>†</b>																						
2700										-		В							Α							Α	
S														_							-						
Second   S					-			-				<u> </u>	-										_				
4700					1																						
S600																					_						
8200  0.010  0.010  0.015  0.018  0.022  0.022  0.033  0.033  0.039  0.047  0.068  0.068  0.068  0.068  0.070  0.080  0.080  0.080  0.080  0.080  0.090  0.090  0.000  0.00000  0.0000  0.0000  0.0000  0.0000  0.0000  0.0000  0.0000  0.00000  0.0000  0.0000  0.0000  0.0000  0.0000  0.0000  0.0000  0.00000  0.0000  0.00000  0.00000  0.00000  0.000000																											
0.010																					T	Т				Α	
(µF) 0.012 0.015 0.018 0.022 0.027 0.033 0.039 0.039 0.047 0.082 0.082 0.082 0.088 0.088 0.082 0.098 0.0080					-			<u> </u>	<u> </u>	<u> </u>	-			_		-											
0.015 0.018 0.022 0.027 0.033 0.039 0.047 0.068 0.068 0.082 0.0100 0.080 0.090 0.000 0.000 0.000 0.000					-			-			-	-		Α	Α	Α	Α				_			A	Α		
0.018 0.022 0.027 0.033 0.039 0.047 0.068 0.068 0.082 0.100 WVDC 16 25 50 16 25 50 16 25 50 16 25 50 16 25 50 100 200 200 200 200 200 200 20								<u> </u>	<u> </u>			<u> </u>	<u> </u>			1	<del>                                     </del>				-				$\vdash$		
0.022 0.027 0.033 0.039 0.047 0.068 0.068 0.082 0.100 WVDC 16 25 50 16 25 50 16 25 50 100 200 16 25 50 100 200 250 16 25 50 100 200 250 500					·	$\geq$	$\leq$	<u>-W</u> -	·																$\vdash$		
0.027 0.033 0.039 0.047 0.068 0.082 0.082 0.0100 WVDC 16 25 50 16 25 50 16 25 50 100 200 16 25 50 100 200 250 16 25 50 100 200 250 500				~	$\sim$			ر (	4_								1										
0.039		0.027						$\square$	<b>↓</b> T :											Н		Н					
0.047				_	_		_		_																$\Box$		
0.068					_											-	-								$\vdash$		
0.082						₹ T			-	-	<del>                                     </del>	-	-		-	+-	-								$\vdash$		
0.100						<u> </u>				<del>                                     </del>																	
WVDC 16 25 50 16 25 50 16 25 50 16 25 50 16 25 50 100 200 16 25 50 100 200 250 16 25 50 100 200 250 50					1																						
SIZE 0101* 0201 0402 0603 0805 1206						16		50	16	25			200	16	25			200	250					200	250	500	
	S	IZE	0101*	02	.01		0402				0603						0805						1206				

Case Size	0101 (KGM 02)	0201 (KGM03)	0402 (KGM05)	08	305 (KGM2	1)	1206 (KGM31)								
Thickness Letter	Α	А	Α	Α	В	В	Е	Α	В	V	Т	D	Α	Н	
Max Thickness (mm)	0.22	0.33	0.55	0.90	0.95	0.94	1.35	1.45	0.94	1.22	1.35	1.45	1.80	1.90	
Carrier Tape	PAPER	PAPER	PAPER	PAPER	PAPER	PAPER	EMB	EMB	PAPER	EMB	EMB	EMB	EMB	EMB	
Packaging Code 7"reel	Н	Н	Н	T	Т	T	U	U	T	U	U	U	U	U	
Packaging Code 13"reel	n/a	N	N	М	М	М	L	L	М	L	L	L	L	L	
		ı	PAPER			EMBOSSED (EMB)									

# **COG (NPO) Dielectric, KGM Series**





S	IZE			1210			1812						1825			2220		2225			
	dering			Reflow Onl	V		Reflow Only					F	Reflow On	v	F	Reflow On	ly	R	eflow Only	,	
	kaging			II Embosse			All Embossed					All Embossed				II Emboss			Embosse		
(L)	mm			3.20 ± 0.20			4.50 ± 0.30						4.50 ± 0.3			5.70 ±0.40			.72 ±0.25		
Length	(in.)		(0	0.126± 0.00	18)		(0.177±0.012)					(0.177 ± 0.012)			(0	.225 ±0.01	16)	(0.2	225 ±0.01	0)	
(W)	mm			2.50±0.20			3.20 ±0.20					6.40 ±0.40				5.00 ±0.40			.35 ±0.25		
Width	(in.)			0.098±0.00					126 ±0.00				0.252±0.01			.197 ±0.01		(0.250 ±0.010)			
(t)	mm			0.50±0.25					0.61 ±0.36				0.61±0.36		\-\\-\\-\-\-\-\-\-\-\-\-\-\-\-\-\-\-\-	0.64 ±0.39	)	0.64 ±0.39			
Terminal	(in.)			0.020±0.01					.024 ±0.01				0.024±0.01			.025 ±0.0		(0.025±0.015)			
WVDC	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200	
	Cap 3.9		- 00	100				- 00				- 00				100	200	- 00		200	
	(pF) 4.7																				
	5.6																				
	6.8															1				-	
	8.2															$\vdash$	· >-	- 4	-10/		
	10	Е	Е	E	E	Е	В	В	В	В	В					H.,		$\sim$	VV		
	12	E	E	E	E	E	В	В	В	В	В					<u> </u>	$\overline{}$	, '	) ÎT		
_	15	E	E	E	E	E	В	В	В	В	В					⊢ (		1 _	₩.	$\overline{}$	
	18	E	E	E	E	E	В	В	В	В	В					-				$\overline{}$	
	22	E	E	E	E	E	В	В	В	В	В		-		-	$\vdash$	4	•		-	
	27	E	E	E	E	E	В	В	В	В	В					+	. 1	i I	I		
	33	E	E	E	E	E	В	В	В	В	В					-	-			$\vdash$	
	33	E	E	E	E	E	В	В	В	В	В					1	-				
	47	E	E	E	E	E	В	В	В	В	В										
	56	E	E	E	E	E	В	В	В	В	В						-				
							В														
	68	E	E	E	E	E		В	В	В	В					1					
	82	E	E	E	E	E	В	В	В	В	В										
	100	E	E	E	E	E	В	В	В	В	В										
	120	E	E	E	E	E	В	В	В	В	В										
	150	E	E	E	E	E	В	В	В	В	В										
	180	E	E	E	E	E	В	В	В	В	В										
	220	E	E	E	E	E	В	В	В	В	В										
	270	E	E	E	E	E	В	В	В	В	В										
	330	E	E	Е	E	E	В	В	В	В	В										
	390	E	E	E	Е	Е	В	В	В	В	В										
	470	E	E	E	E	E	В	В	В	В	В										
	560	Е	E	E	E	Е	В	В	В	В	В										
	680	E	E	E	E	Е	В	В	В	В	В					ļ					
	820	E	E	E	E	Е	В	В	В	В	В										
	1,000	E	E	E	E	Е	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	1200	Е	E	E	E	Е	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	1500	E	E	E	E	E	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	1800	E	E	E	E	E	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	2200	E	E	E	E	E	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	2700	Е	E	E	E	E	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	3300	Е	E	E	E	E	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	3900	E	E	E	E	Е	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	4700	E	E	E	Н	Н	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	5600	Е	E	E	Н	Н	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	6800	Е	E	E	Н	Н	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	8200	Е	E	E	Н	Н	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	Cap 0.010	Е	Е	Н	J	J	В	В	В	В	В	С	С	С	Z	Z	Z	D	D	D	
	(μF) 0.012	Н	Н	Н	J	J	В	В	В	Е	E	С	С	С	Z	Z	Z	D	D	D	
	0.015	Н	Н	J	L	L	В	В	В	Е	E	С	С	С	Z	Z	Z	D	D	D	
	0.018	J	J	L	L		В	В	E	F	F	С	С	С	Z	Z	Z	D	D	D	
	0.022	J	J	L	L		В	В	Е	F	F	С	С	С	Z	Z	Z	D	D	D	
	0.027	L	L	L	L		Е	Е	F	J		С	С	С	Z	Z	Z	D	D	D	
	0.033	L	L	L	L		Е	Е	F			С	С	С	Z	Z	Z	D	D	D	
	0.039	L	L	L			J	J	J			С	С	С	Z	Z	Z	D	D	D	
	0.047	L	L	L	İ		J	J	J			С	С	С	Z	Z	С	D	D	D	
	0.068						J	J	J			С	С	F	Z	Z	С	D	D	G	
	0.082						J	J	J			С	F		Z	C		D	D	G	
	0.100						J	J	J			F	F		C	C		D	G	G	
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200	
	SIZE			1210					1812				1825			2220			2225		
	J.LL																				

Case Size		1210 (KGI	M 32)			18	12 (KGM 4	13)		1825 (k	(GM 44)	22	20 (KGM 5	2225 (KGM56)		
Thickness Letter	E	Н	J	L	В	Е	F	J	С	F	Z	С	D	G	Е	G
Max Thickness (mm)	1.45	1.8	2.21	2.80	1.45	1.8	2.21	2.80	2.21	2.80	2.21	2.80	2.21	2.80	2.29	2.80
Carrier Tape	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB	EMB
Packaging Code 7"reel	U	U	U	U	V	V	٧	٧	٧	٧	٧	٧	٧	٧	V	V
Packaging Code 13"reel	L	L	L	L	S	S	S	S	S	S	S	S	S	S	S	S
								EMBOS	SED (EME	3)						

